

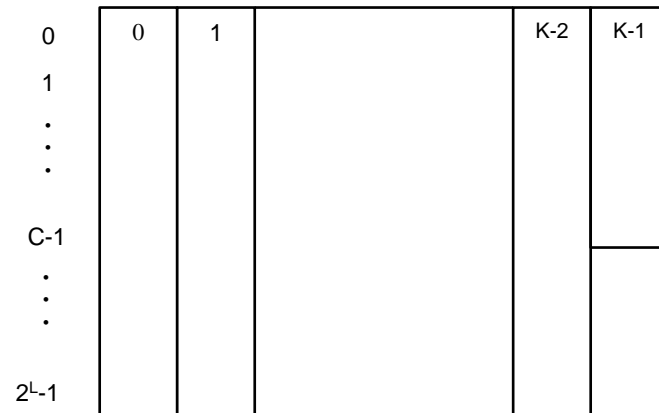
# FREQUENCY INTERLEAVER PERFORMANCE IN LTE INTERFERENCE

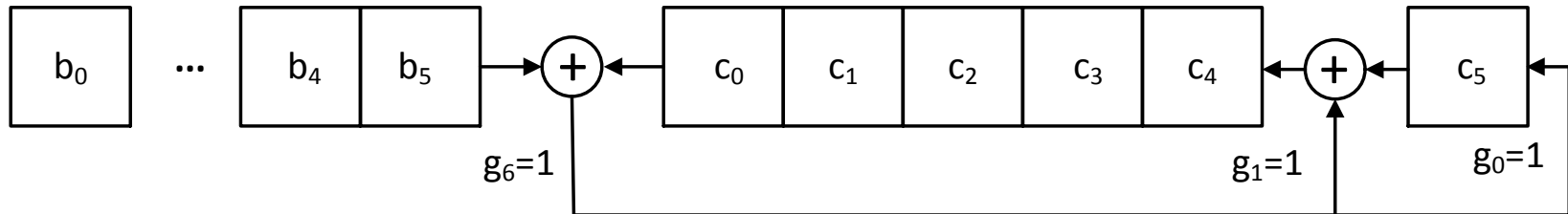


Presenter: Rich Prodan

# *EPoC Downstream Frequency Interleaver*

- 2-D store
- $2^L$  rows and  $K$  columns
- $L$  and  $K$  are chosen depending on FFT size
- $N_I$  data subcarriers and scattered pilots
- $K = \text{ceil}(\frac{N_I}{2^L})$
- $C = N_I - 2^L(K - 1)$   
subcarriers in the last column



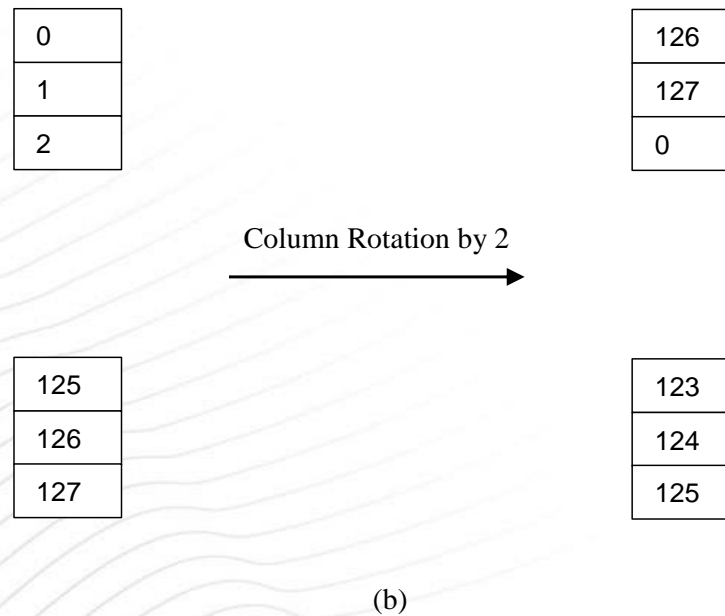
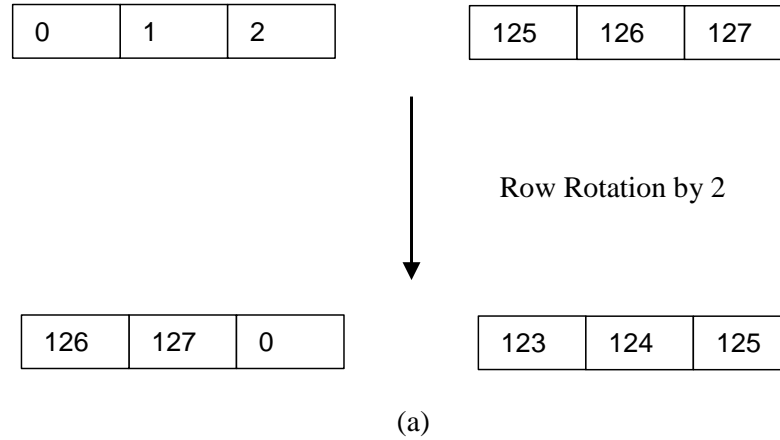


- **6-stage linear feedback shift register (LFSR) for calculating the CRC of each row address**
- **Defined using a primitive generator polynomial of degree 6:**
$$G(X) = X^6 + X^1 + 1$$
- **Input sequential row address  $b_5, b_4, b_3, b_2, b_1, b_0$**
- **Output permuted row address = CRC value  $c_5, c_4, c_3, c_2, c_1, c_0$**

- Write successive consecutive subcarriers into the 2-D store in the row given by the L bit CRC value of each L bit row address.
- Rotate the subcarriers in each row written by the same L bit CRC value of the row address modulo the number of columns in that row (either modulo K for a row below C or modulo K-1 for row C and higher) using a right circular shift.
- Rotate the subcarriers in each column by the L bit CRC value of [K-1 minus the column address] using a downward circular shift. Note that the last column K-1 with a CRC value of 0 is not rotated.
- Read the subcarriers out of the 2-D store column-wise from row 0, column 0 to row C-1, column K-1.



# ROW AND COLUMN ROTATION



- **Permuted output subcarrier number in the 2-D store in row  $r$ , column  $c$  as  $sc(r,c)$  given by:**

$$sc(r, c) = sc_0 \left[ \left( r - CRC(K - 1 - c) \right) \bmod 2^L \right] + \left( c - \left( r - CRC(K - 1 - c) \right) \bmod 2^L \right) \bmod M,$$

$$\text{where } M = \begin{cases} K, & \text{for } \left( r - CRC(K - 1 - c) \right) \bmod 2^L < C \\ K - 1, & \text{otherwise} \end{cases}$$

- **$sc_0[n]$  is an array of  $2^L$  elements where each element contains the cumulative number of subcarriers previously written into the 2-D store**
  - Represents the starting (i.e. lowest) subcarrier number in a permuted row
- **Note that if the last column contains fewer subcarriers than  $2^L$ , the cumulative value in  $sc_0[n]$  takes into account those previously written permuted output rows that were shorter by one subcarrier**
- ***Large 2-D store Lookup Table is not needed***
- ***Direct calculation without variable number of clock cycles***

- Write the subcarriers into the 2-D store column-wise from column 0, row 0 to column  $K-1$ , row  $C-1$ .
- Rotate the subcarriers in each column by the  $L$  bit CRC value of [ $K-1$  minus the column address] using an upward circular shift (reverse of interleaver). Note that the last column  $K-1$  with a CRC value of 0 is not rotated.
- Rotate the subcarriers in each row written by the same  $L$  bit CRC value of the row address modulo the number of columns in that row (either modulo  $K$  for a row below  $C$  or modulo  $K-1$  for row  $C$  and higher) using a left circular shift (reverse interleaver).
- Read the subcarriers out of the 2-D store row-wise in the row order given by the  $L$  bit CRC value of each  $L$  bit row address skipping the last column at or beyond row  $C$ .



# EPoC INTERLEAVER OUTPUT (PARTIAL)



<b># Subcarriers</b>	<b>3745</b>
<b># Rows</b>	<b>64</b>
<b># Columns</b>	<b>59</b>
<b>Last Column</b>	<b>33</b>

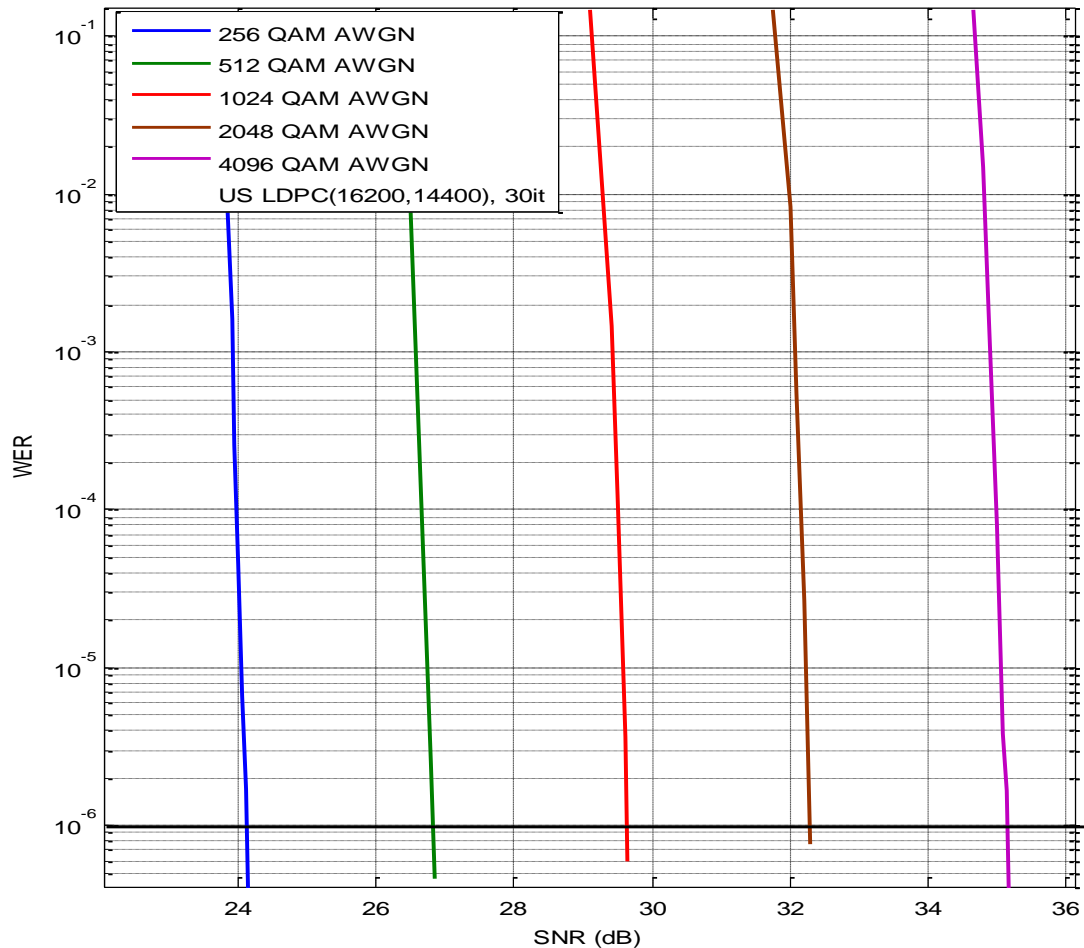
Read	Column 0	Write	Column 0	COLUMN:	0	1	2	3	4	5	6	7	8
ROW	Subcarrier	ROW	Subcarrier	Rotation:	44	4	52	22	38	14	62	26	42
0	0	0	0	0	390	350	283	2944	3020	2821	2870	3186	3262
1	1930	48	59	48	2319	2162	2212	1130	1089	1007	939	1372	1331
2	2866	24	117	24	3254	3097	3147	3410	3486	3287	3336	201	160
3	936	40	176	40	1323	1283	1216	1596	1555	1473	1405	2013	2089
4	3334	12	234	12	152	1	3731	659	618	536	468	2948	3024
5	1404	60	293	1	2081	1930	1799	2471	2547	2348	2456	1134	1093
6	468	20	351	20	3016	2924	862	72	3658	3517	3625	3414	3490
7	2398	36	410	36	1085	993	2791	1884	1843	1703	1694	1600	1559
8	3568	6	468	6	3482	3390	392	2819	906	766	757	663	622
9	1638	54	527	54	1551	1459	2321	1005	2718	2578	2686	2475	2551
10	702	30	585	30	614	522	3256	3285	436	296	287	76	3662
11	2632	46	644	46	2543	2451	1325	1471	2248	2108	2216	1888	1847
12	234	10	702	10	3654	3620	154	534	3183	3043	3151	2823	910
13	2164	58	761	58	1839	1689	2083	2346	1369	1229	1220	1009	2722
14	3100	18	819	18	902	752	3018	3515	198	5	3735	3289	440
15	1170	34	878	34	2714	2681	1087	1701	2010	1934	1803	1475	2252

# *LTE Interference Model*

- **10 MHz wide LTE interference placed in the center of the 190 MHz OFDM band**
  - LTE PSD -20 dB below the PSD of the OFDM signal (moderate)
  - LTE PSD -3 dB below the PSD of the OFDM signal (strong)
- **A 4K FFT with 50 kHz subcarrier spacing would affect 200 subcarriers out of 3800 subcarriers in 190 MHz**
- **Modulation orders of 4096-QAM, 1024-QAM, and 256-QAM**
- **Performance with and without frequency interleaving simulated**
- **The increased SNR threshold of the AWGN background under LTE interference with frequency interleaving shown**

*EPoC Frequency Interleaver  
Performance in LTE  
Interference*

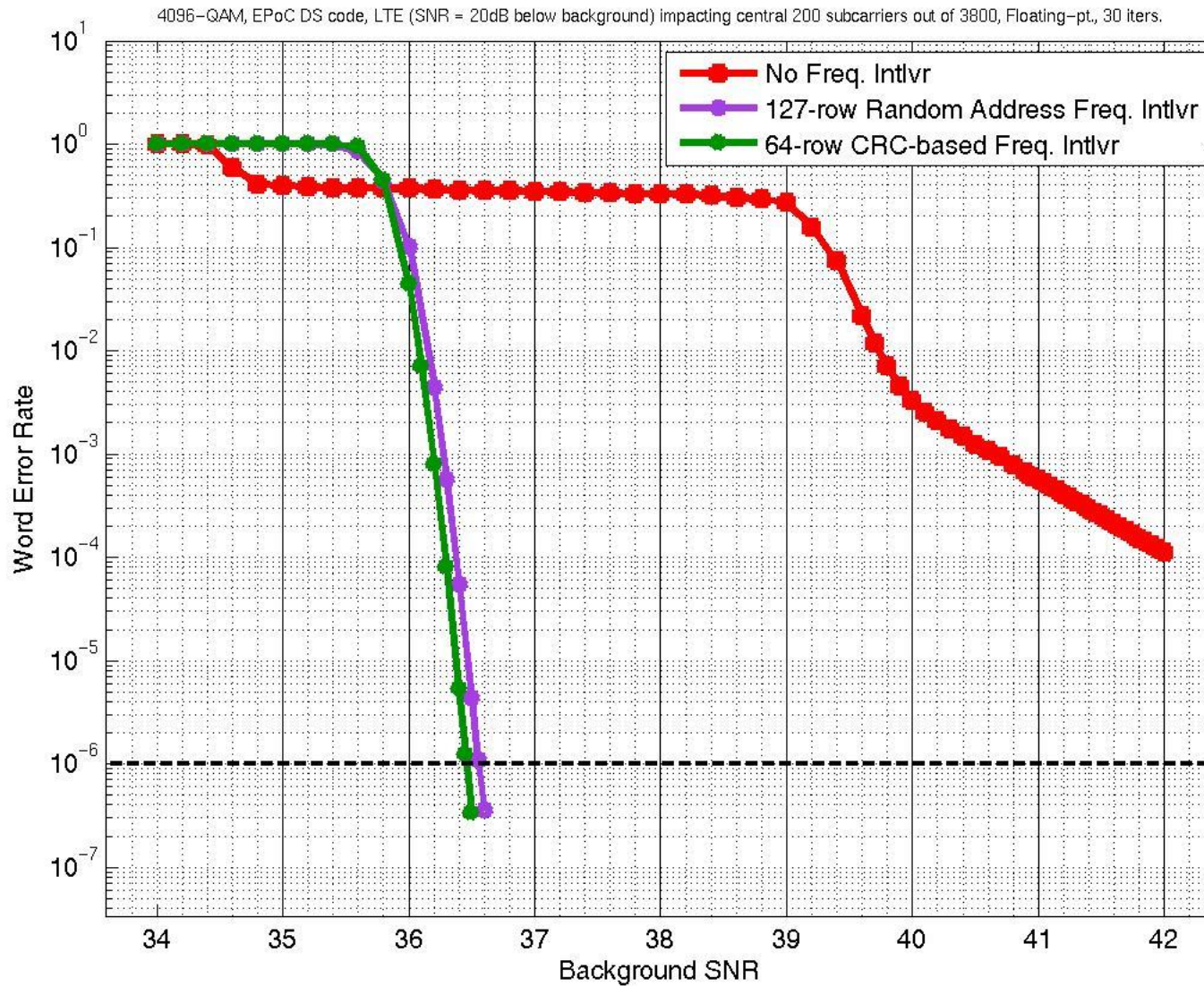
# FEC PERFORMANCE IN AWGN CHANNEL



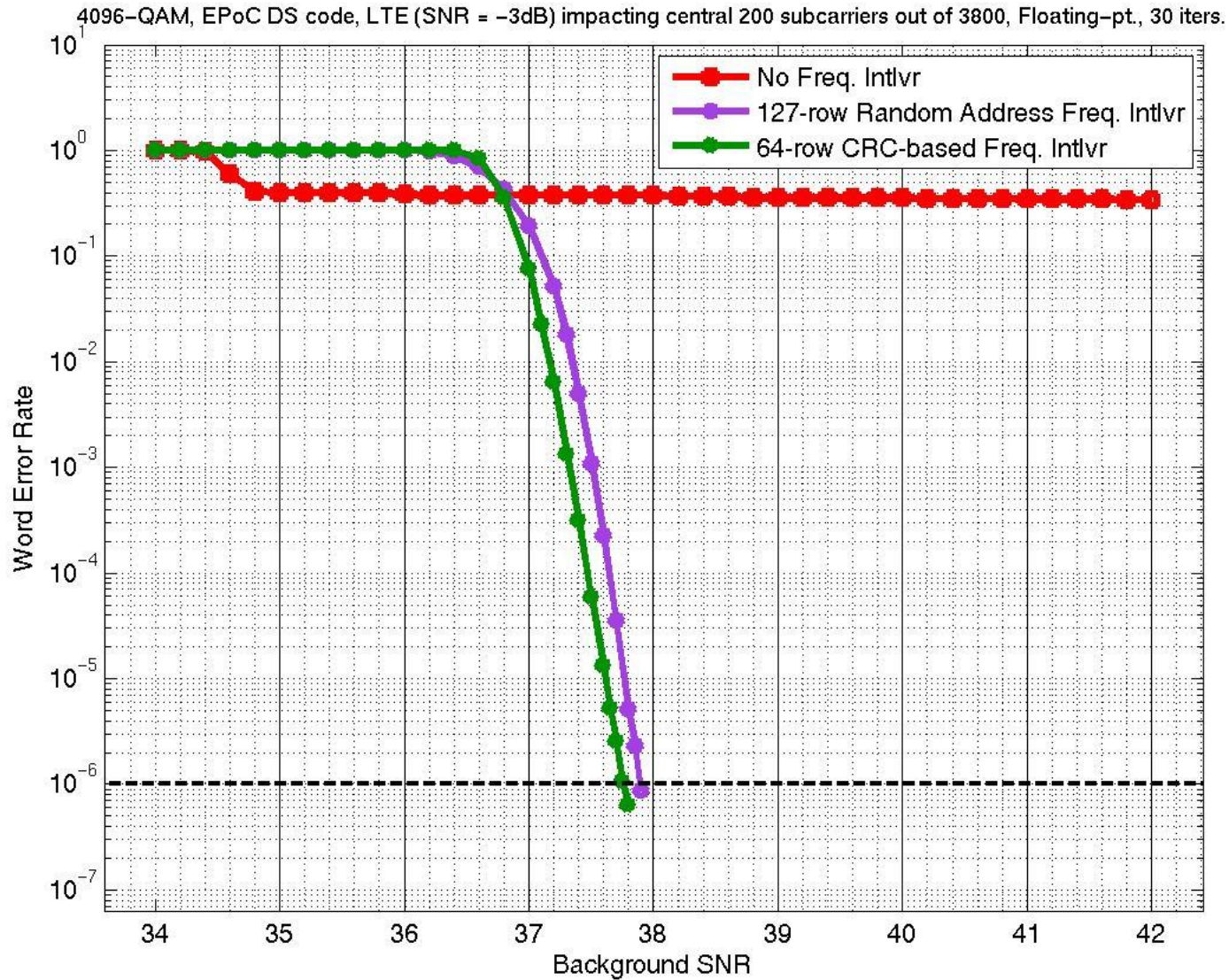
Downstream (16200, 14400) code (30 iterations)		256QAM	512QAM	1024QAM	2048QAM	4096QAM
	<b>SNR@WER=1e-6</b>	24.11dB	26.83dB	29.64dB	32.29dB	35.16dB
	<b>SNR@BER=1e-8</b>	24.1dB	26.82dB	29.62dB	32.28dB	35.15dB



# 4096-QAM IN -20 dB 10 MHz LTE INTERFERENCE

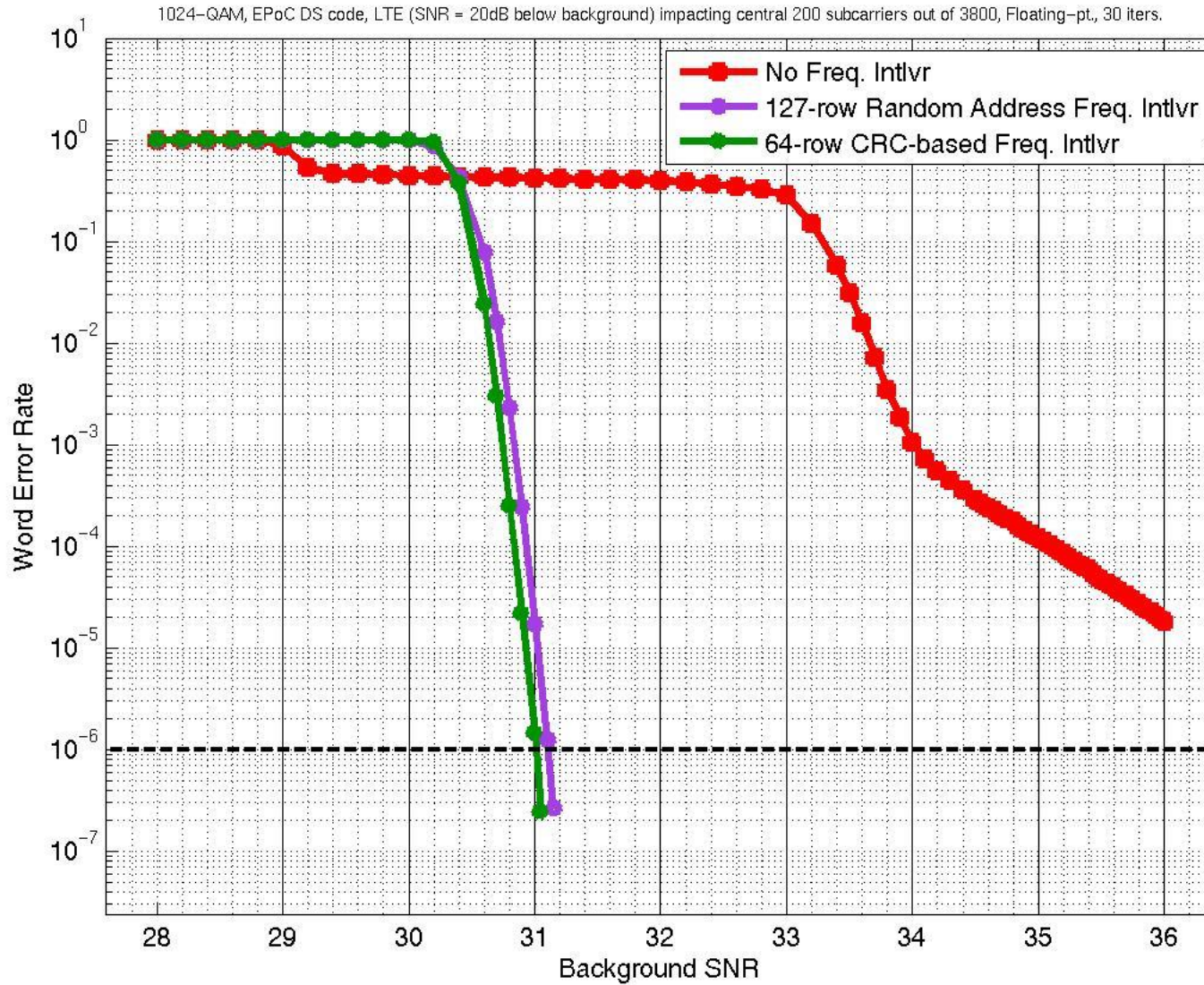


# 4096-QAM IN -3 dB 10 MHz LTE INTERFERENCE

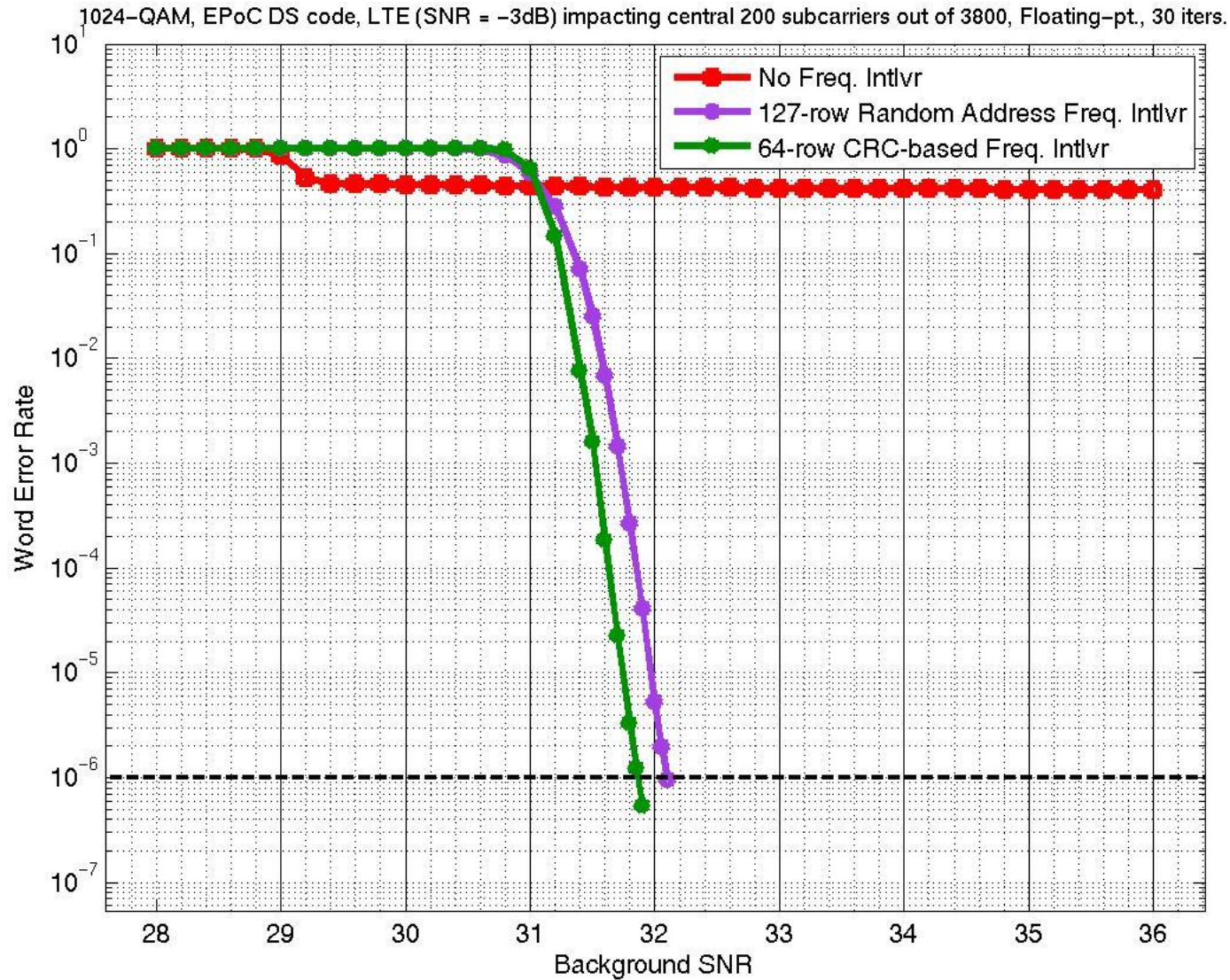




# 1024-QAM IN -20 dB 10 MHz LTE INTERFERENCE

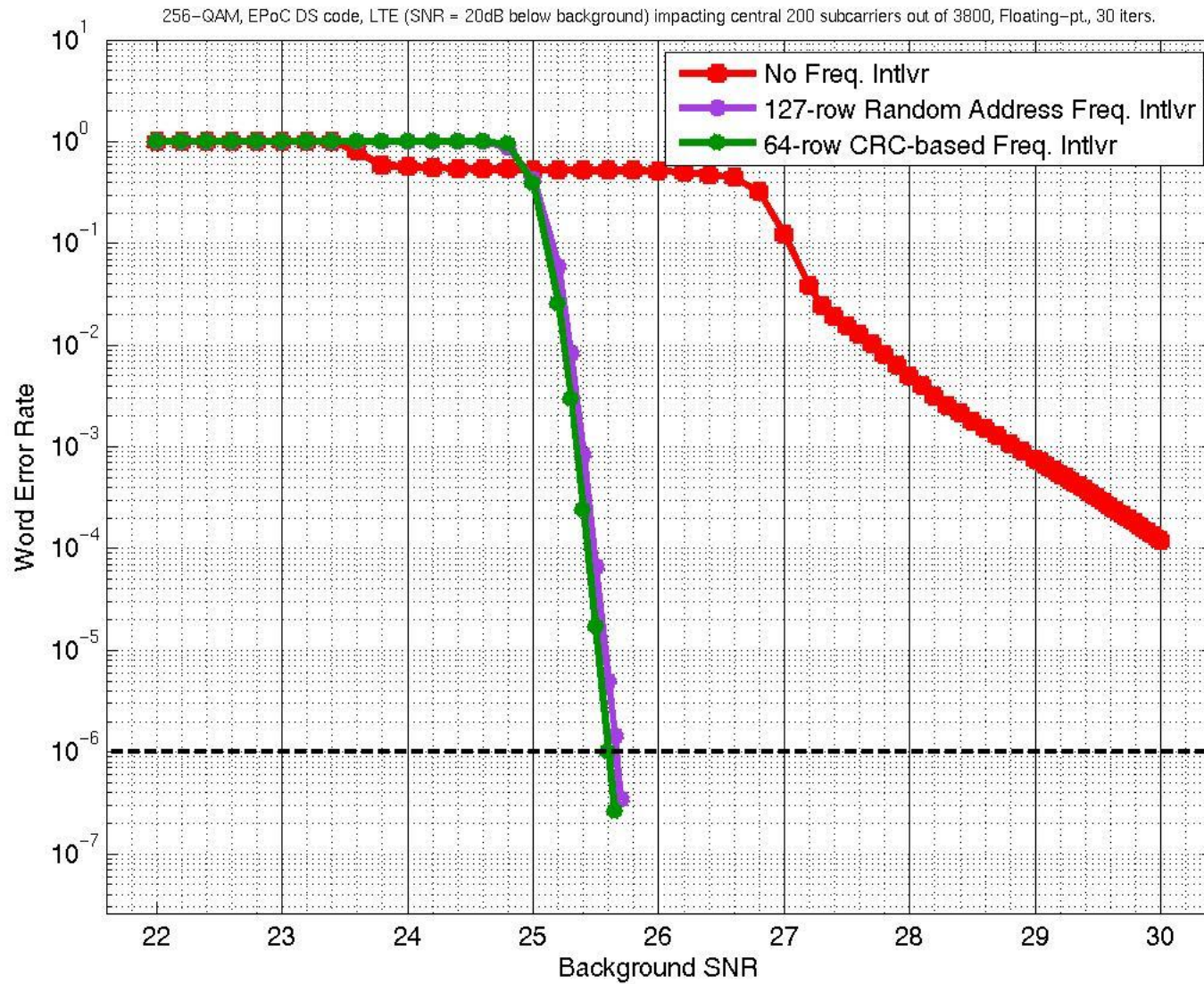


# 1024-QAM IN -3 dB 10 MHz LTE INTERFERENCE



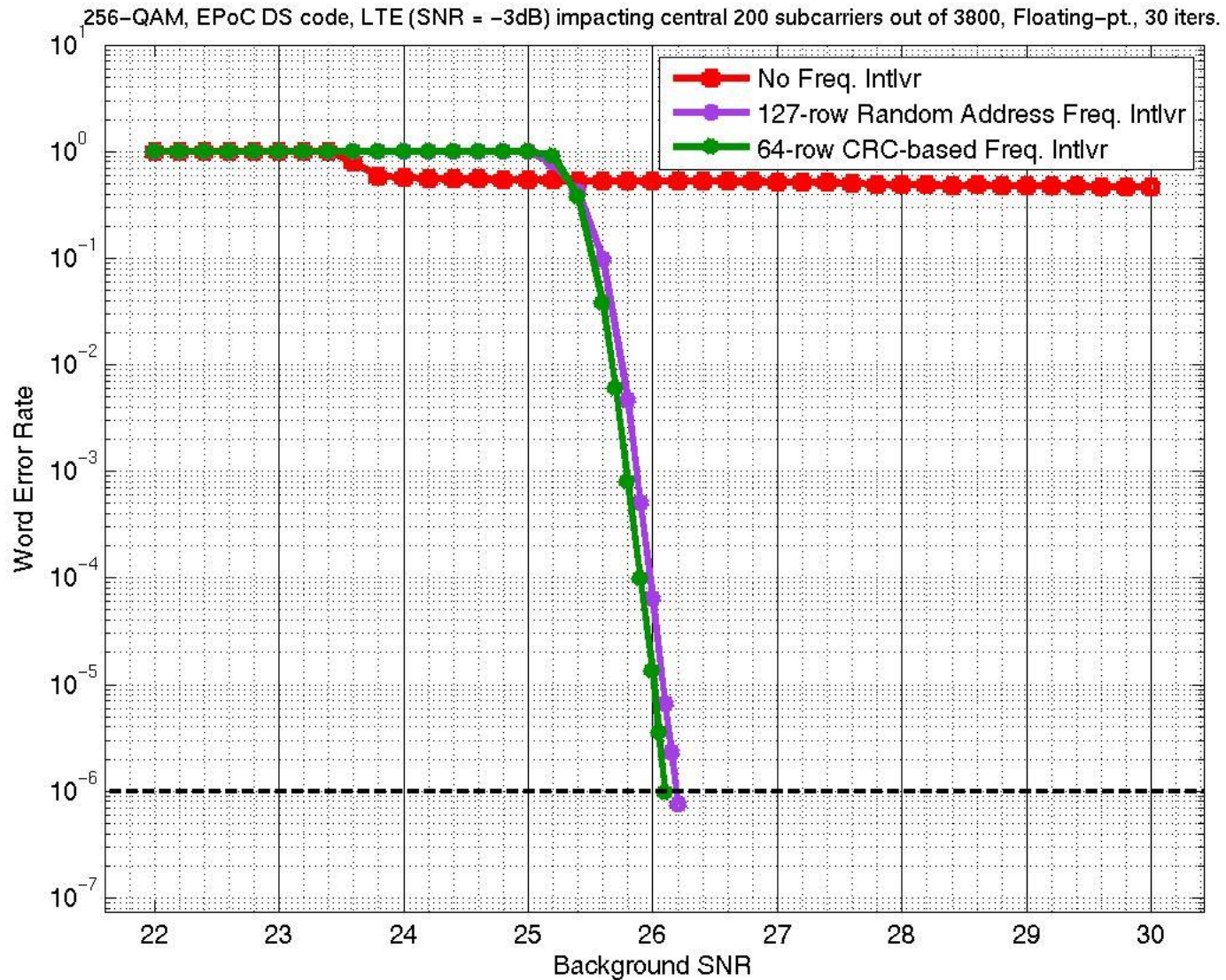


# 256-QAM IN -20 dB 10 MHz LTE INTERFERENCE





# 256-QAM IN -3 dB 10 MHz LTE INTERFERENCE



- **2-D Random (non-systematic) frequency interleaver described**
  - CRC encoded row write addressing at the input
  - CRC encoded rotation of both rows and columns to prevent periodicity
  - Sequential column read addressing at the output
  - Provides pseudo-random subcarrier frequency dispersion
  - Non-systematic random ordering of subcarriers across the entire spectrum
- **10 MHz wide LTE interferer in the center of a 190 MHz OFDM band at both moderate and strong interference levels simulated**
- **Modulation orders of 4096-QAM, 1024-QAM, and 256-QAM evaluated**
- **Frequency interleaver improved performance in LTE interference has been demonstrated**
- **Noise margin loss in AWGN with LTE interference determined**
  - Less than 1.5 dB better SNR needed with a moderate -20 dB LTE interferer
  - Less than 2.5 dB better SNR needed with a strong -3 dB LTE interferer

*Thank You*